## NSN 5961-00-463-3400

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View Online at https://aerobasegroup.com/nsn/5961-00-463-3400 **Inclosure Material:** Metal **Overall Length:** 0.355 inches **Terminal Length:** 0.420 inches **Overall Diameter:** 0.870 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 breakdown voltage, collector-to-base, emitter open and 10.0 emitter to base voltage, static, collector open and 80.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 5.00 amperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 90.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 3 wire hook Shelf Life: N/a

Demilitarization: Yes - demil/mli

**Unit Of Measure:** 

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